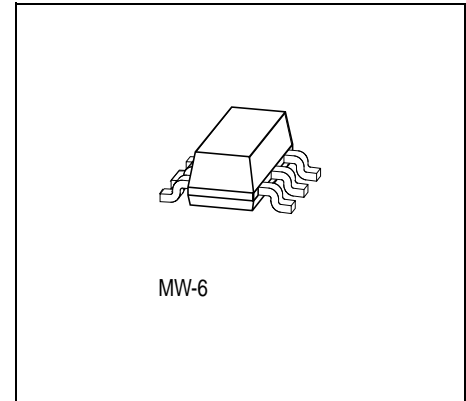


GaAs MMIC

Data Sheet

CGY 121 B

- Variable gain amplifier (MMIC-Amplifier) for mobile communication
- Gain Control range over 50 dB
- Positive Control Voltage
- 50 Ω input and output matched
- Low power consumption
- Operating voltage range: 2.7 to 6 V
- Frequency range 800 MHz ... 2.5 GHz



ESD: **E**lectro**S**tatic **d**ischarge sensitive device, observe handling precautions!

Type	Marking	Ordering Code (taped)	Package ¹⁾
CGY 121 B	Y0S	Q62702-G0071	MW-6

¹⁾ Dimensions see **Page 11**.

Maximum Ratings	Symbol	Value	Unit
Drain voltage	V_D	8	V
Neg. supply voltage	V_G	- 8	V
Pos. control voltage	V_{con}	4	V
Channel temperature	T_{Ch}	150	$^{\circ}\text{C}$
Storage temperature range	T_{stg}	- 55 ... + 150	$^{\circ}\text{C}$
Total power dissipation ($T_S \leq 81 \text{ }^{\circ}\text{C}$) ¹⁾	P_{tot}	550	mW

¹⁾ Please care for sufficient heat dissipation on the pcb!

Thermal Resistance	Symbol	Value	Unit
Channel-soldering point (GND)	R_{thChS}	125	K/W

Functional Block Diagram

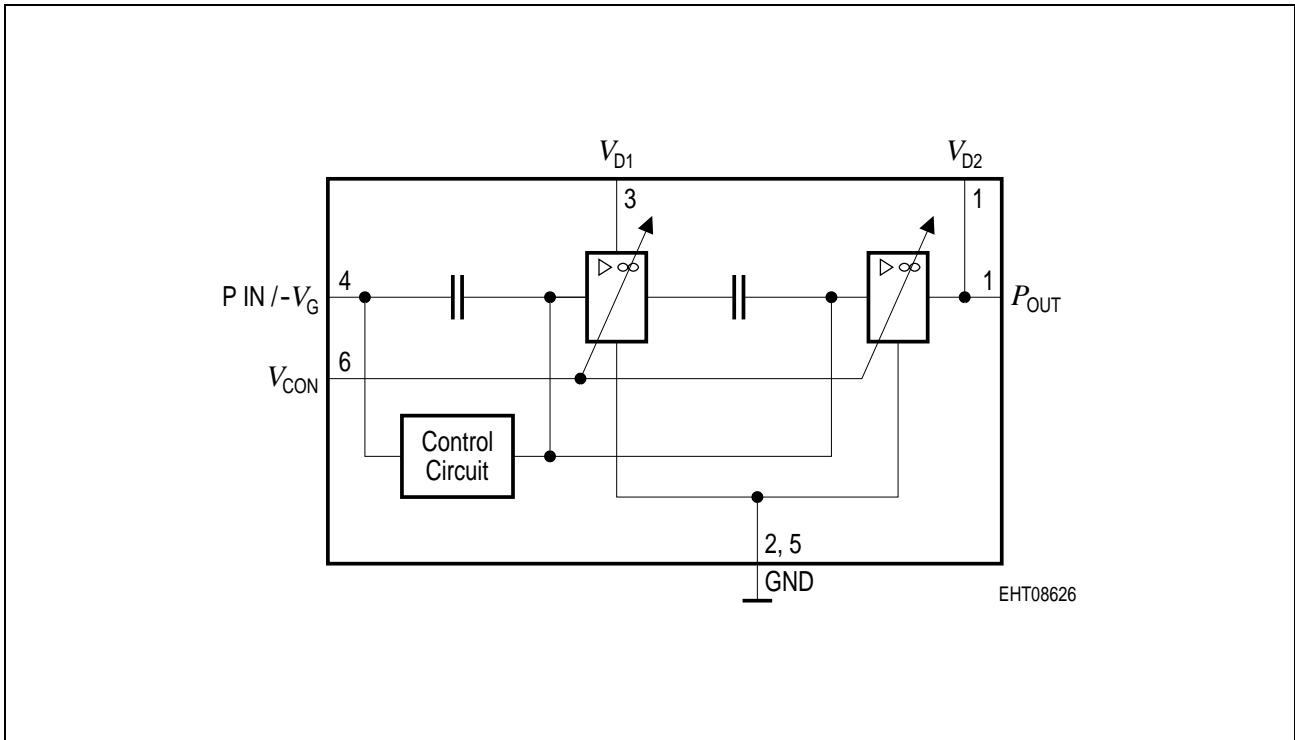


Figure 1

Pin #	Symbol	Configuration
1	VD2/Pout	Drain voltage 2 nd stage/RF-Output
2	RF-Gnd	–
3	VD1	Drain voltage 1 st stage
4	VG/Pin	Negative voltage at current control circuit (– 4 V)/RF-Input
5	RF-Gnd	–
6	Vcontrol	Positive voltage for gain control (0 V ... 3 V)

Electrical Characteristics
 $T_A = 25\text{ °C}, f = 900\text{ MHz}, V_g = -4\text{ V}, R_S = R_L = 50\text{ }\Omega$; unless otherwise specified

Characteristics	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Power Gain	G	–	20.5	–	dB	$V_d = 3\text{ V};$ $V_{con} = 3\text{ V}$
Input return loss	RL_{in}	–	13	–	dB	$V_d = 3\text{ V};$ $V_{con} = 3\text{ V}$
Output return loss	RL_{out}	–	11	–	dB	$V_d = 3\text{ V};$ $V_{con} = 3\text{ V}$
Gain Control Range	dG	–	54	–	dB	$V_{con} = 3\text{ V} \dots 0\text{ V};$ $V_d = 3\text{ V}$
1 dB gain compression	$P_{1dB\ out}$	–	15	–	dBm	$V_d = 3\text{ V};$ $V_{con} = 3\text{ V}$

Electrical Characteristics
 $T_A = 25\text{ °C}, f = 1800\text{ MHz}, V_g = -4\text{ V}, R_S = R_L = 50\text{ }\Omega$; unless otherwise specified

Characteristics	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Power Gain	G	–	19.5	–	dB	$V_d = 3\text{ V};$ $V_{con} = 3\text{ V}$
Input return loss	RL_{in}	–	10	–	dB	$V_d = 3\text{ V};$ $V_{con} = 3\text{ V}$
Output return loss	RL_{out}	–	9	–	dB	$V_d = 3\text{ V};$ $V_{con} = 3\text{ V}$
Gain Control Range	dG	–	53	–	dB	$V_{con} = 3\text{ V} \dots 0\text{ V};$ $V_d = 3\text{ V}$
1 dB gain compression	$P_{1dB\ out}$	–	15	–	dBm	$V_d = 3\text{ V};$ $V_{con} = 3\text{ V}$

DC Characteristics

Characteristics	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Gate current (Pin 4)	I_g	–	1.0	–	mA	$V_d = 3\text{ V}$, $V_g = -4\text{ V}$
Control current (Pin 6)	I_c	–	0.5	–	mA	$V_d = 3\text{ V}$, $V_g = -4\text{ V}$, $V_{con} = 0\text{ V} \dots 3\text{ V}$
Supply current	I_d	–	70	–	mA	$V_d = 3\text{ V}$, $V_g = -4\text{ V}$, $V_{con} = 3\text{ V}$

Electrical Characteristics
 $T_A = 25\text{ °C}$, $f = 900\text{ MHz}$, $V_g = -4\text{ V}$, $R_S = R_L = 50\text{ }\Omega$; unless otherwise specified

Characteristics	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Power Gain	G	–	21	–	dB	$V_d = 5\text{ V}$; $V_{con} = 3\text{ V}$
Input return loss	RL_{in}	–	13	–	dB	$V_d = 5\text{ V}$; $V_{con} = 3\text{ V}$
Output return loss	RL_{out}	–	11	–	dB	$V_d = 5\text{ V}$; $V_{con} = 3\text{ V}$
Gain Control Range	dG	–	54	–	dB	$V_{con} = 3\text{ V} \dots 0\text{ V}$; $V_d = 5\text{ V}$
1 dB gain compression	$P_{1dB\ out}$	–	16	–	dBm	$V_d = 5\text{ V}$; $V_{con} = 3\text{ V}$

Electrical Characteristics
 $T_A = 25\text{ °C}$, $f = 1800\text{ MHz}$, $V_g = -4\text{ V}$, $R_S = R_L = 50\text{ }\Omega$; unless otherwise specified

Characteristics	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Power Gain	G	–	20	–	dB	$V_d = 5\text{ V}$; $V_{con} = 3\text{ V}$
Input return loss	RL_{in}	–	10	–	dB	$V_d = 5\text{ V}$; $V_{con} = 3\text{ V}$
Output return loss	RL_{out}	–	9	–	dB	$V_d = 5\text{ V}$; $V_{con} = 3\text{ V}$
Gain Control Range	dG	–	54	–	dB	$V_{con} = 3\text{ V} \dots 0\text{ V}$; $V_d = 5\text{ V}$
1 dB gain compression	$P_{1dB\ out}$	–	16	–	dBm	$V_d = 5\text{ V}$; $V_{con} = 3\text{ V}$

DC Characteristics

Characteristics	Symbol	Limit Values			Unit	Test Conditions
		min.	typ.	max.		
Gate current (Pin 4)	I_g	–	1.3	–	mA	$V_d = 5\text{ V}$, $V_g = -4\text{ V}$
Control current (Pin 6)	I_c	–	0.8	–	mA	$V_d = 5\text{ V}$, $V_g = -4\text{ V}$, $V_{con} = 0\text{ V} \dots 3\text{ V}$
Supply current	I_d	–	75	–	mA	$V_d = 5\text{ V}$, $V_g = -4\text{ V}$, $V_{con} = 3\text{ V}$

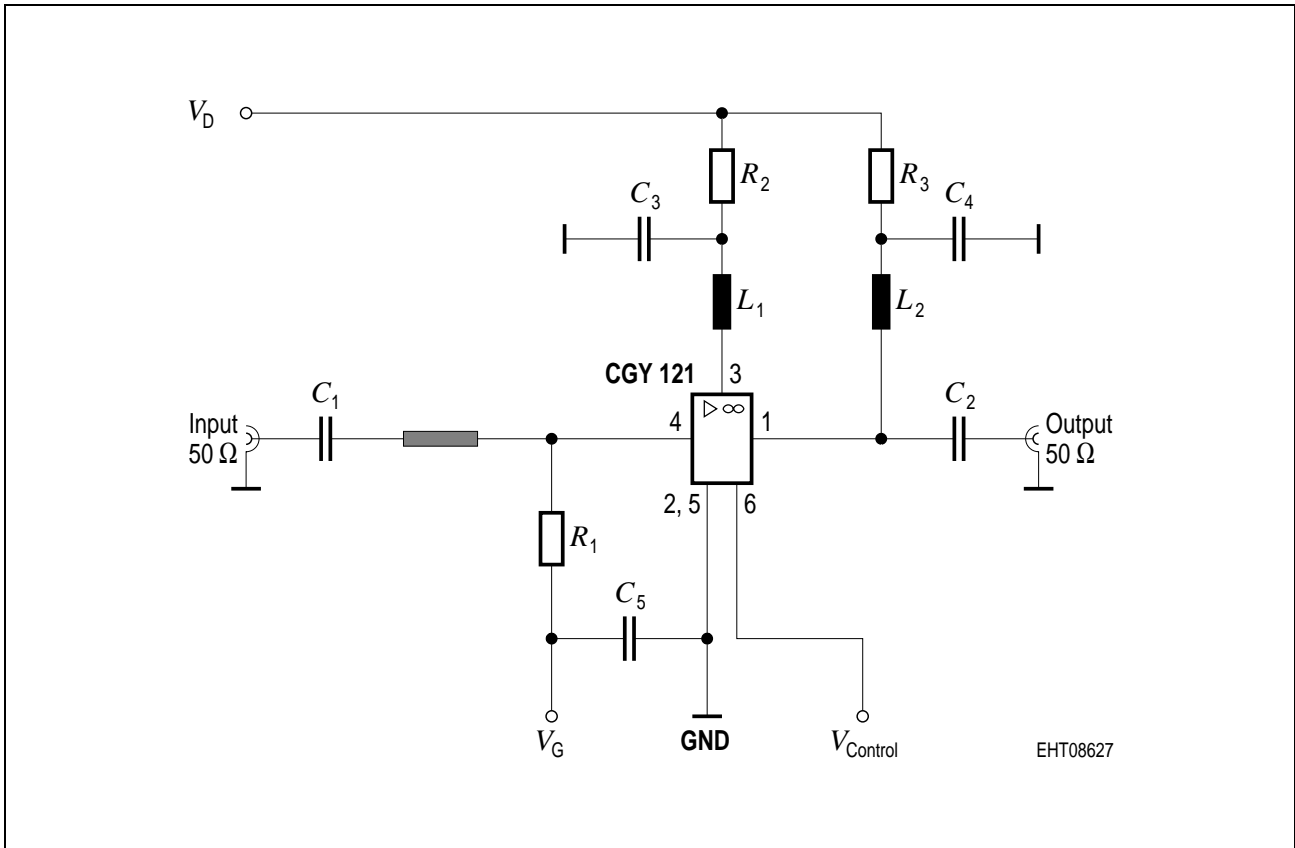


Figure 2 Application Circuit: $f = 900$ MHz

Parts List ($f = 900$ MHz)

C_1, C_2	22 pF	$C_1 \dots C_5$ Epcos Size 0603
C_3, C_4	100 nF	
C_5	47 nF	
L_1	15 nH	Coilcraft 0805CS-150XKBC
L_2	27 nH	Coilcraft 0805CS-270XMBC
R_1	270 Ω	Epcos B 54102-A1271-J60
R_2	12 Ω	Epcos B 54102-A1120-J60
R_3	6.8 Ω	Epcos Size 0805

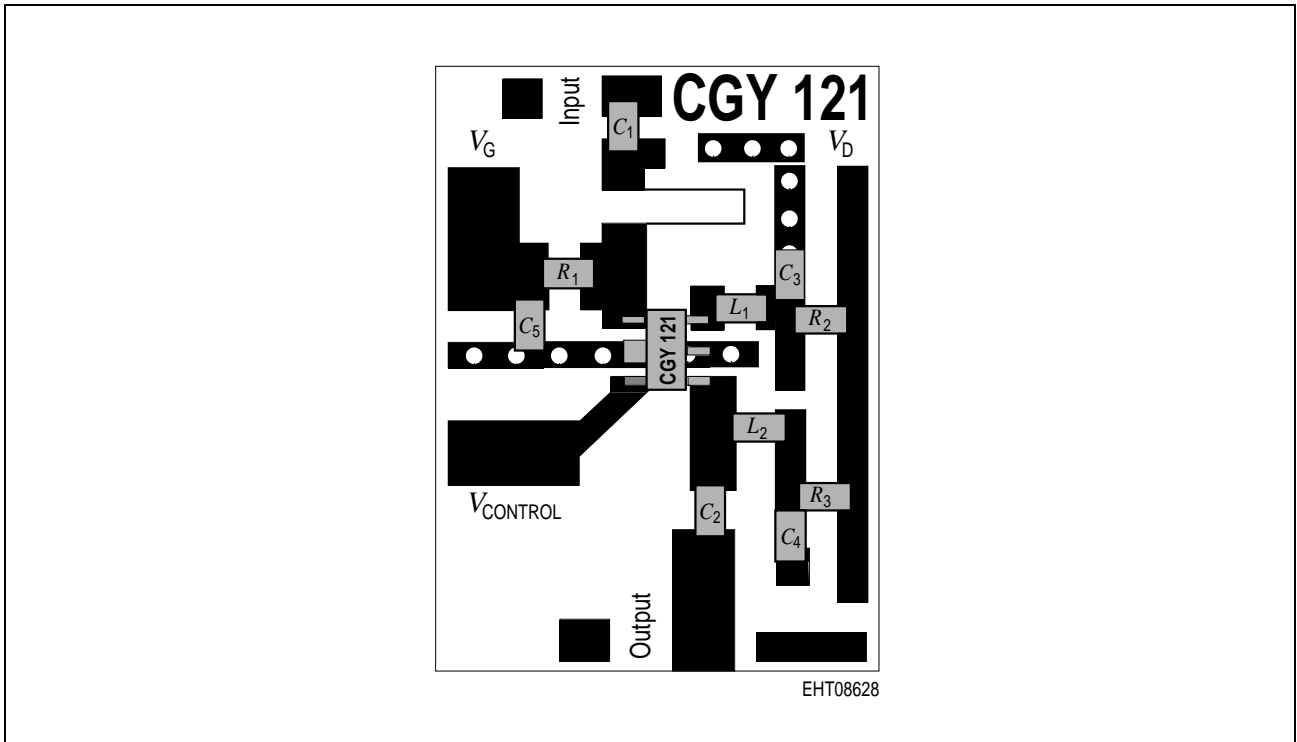


Figure 3

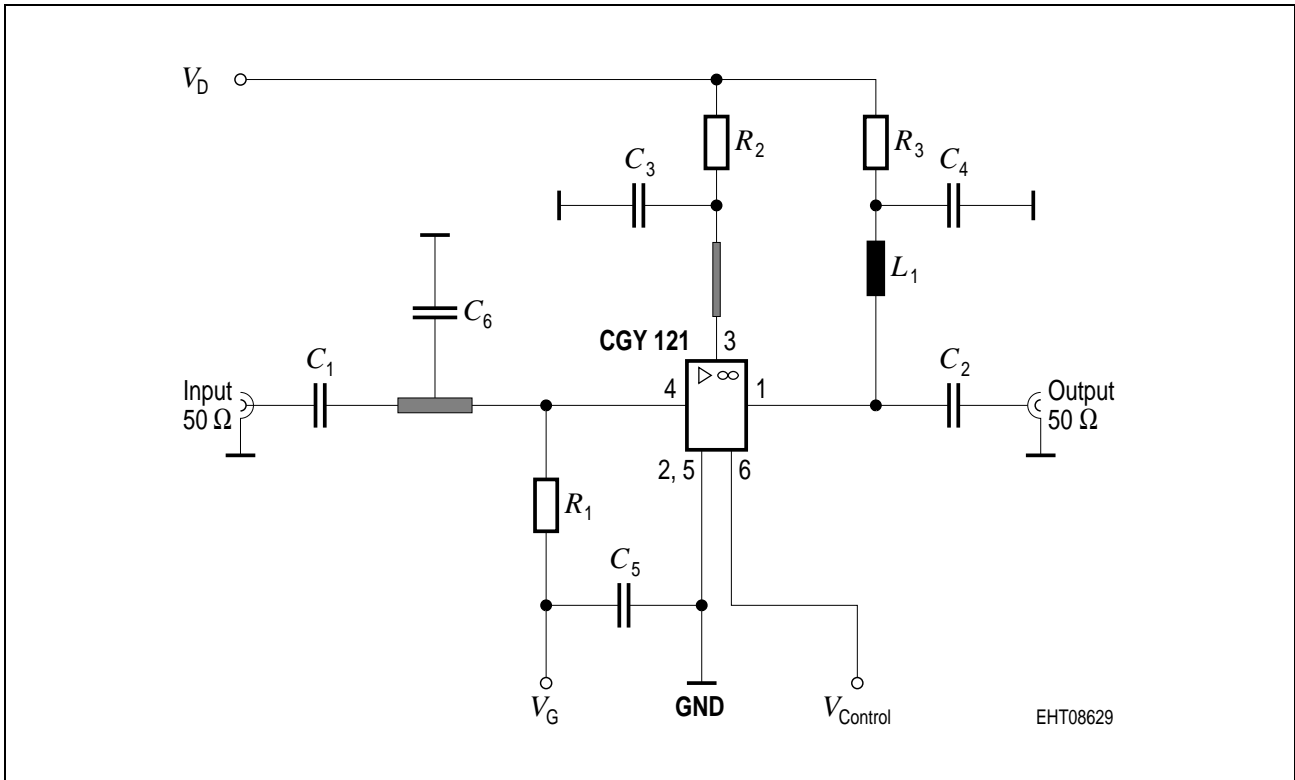


Figure 4 Application Circuit: $f = 1800$ MHz

Parts List ($f = 1800$ MHz)

C_1, C_2	12 pF	$C_1 \dots C_6$ Epcos size 0603
C_3, C_4	100 nF	
C_5	47 nF	
C_6	1.2 pF	
L_1	15 nH	L_1 Coilcraft 0805CS-270XKBC
R_1	270 Ω	R_1 Epcos B 54102-A1271-J60
R_2	12 Ω	R_2 Epcos B 54102-A1120-J60
R_3	6.8 Ω	R_3 Epcos Size 0805

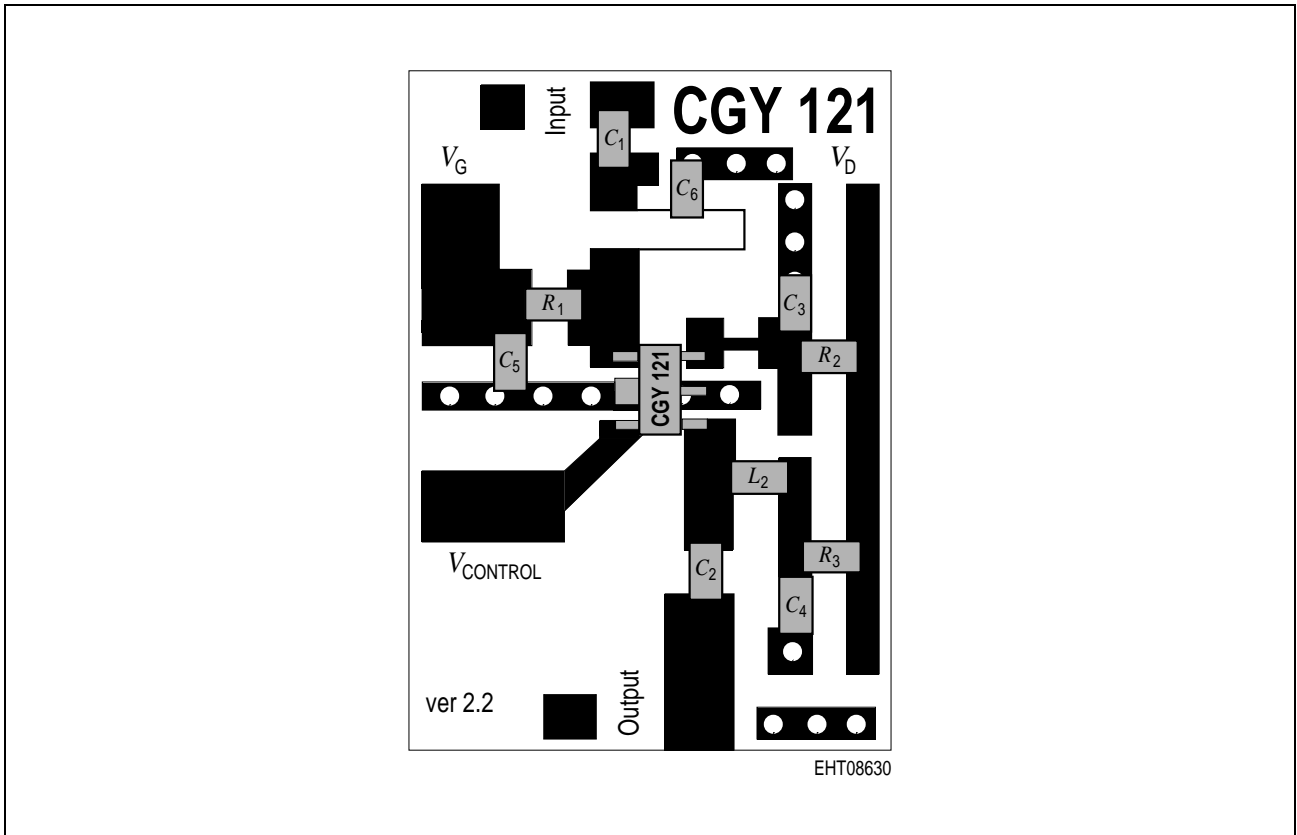
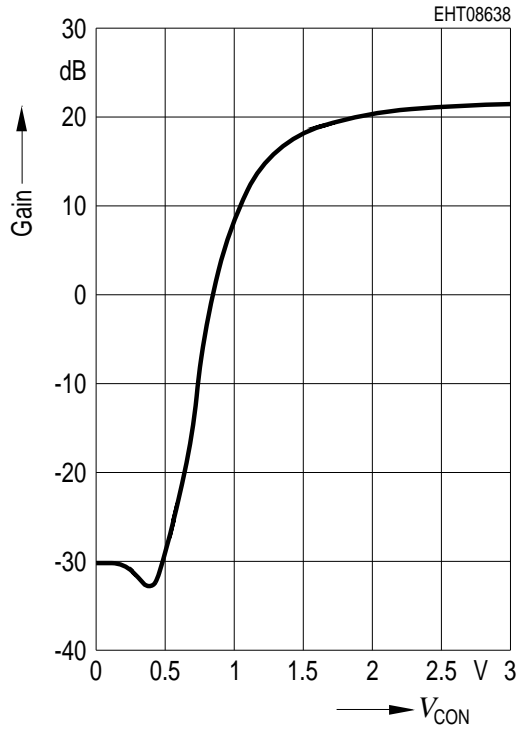
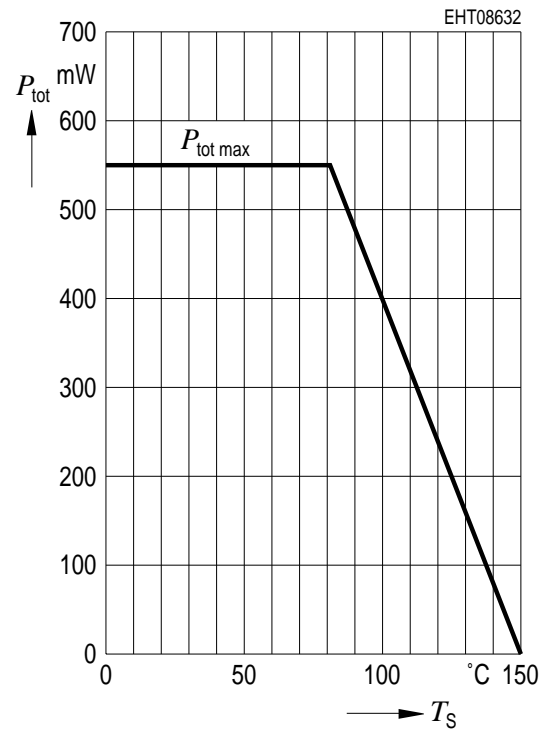


Figure 5

Gain vs. V_{control} , Operating Conditions:
 $V_{\text{d}} = 3 \text{ V}$, $V_{\text{g}} = -4 \text{ V}$, $f = 900 \text{ MHz}$,
 $P_{\text{in}} = -10 \text{ dBm}$

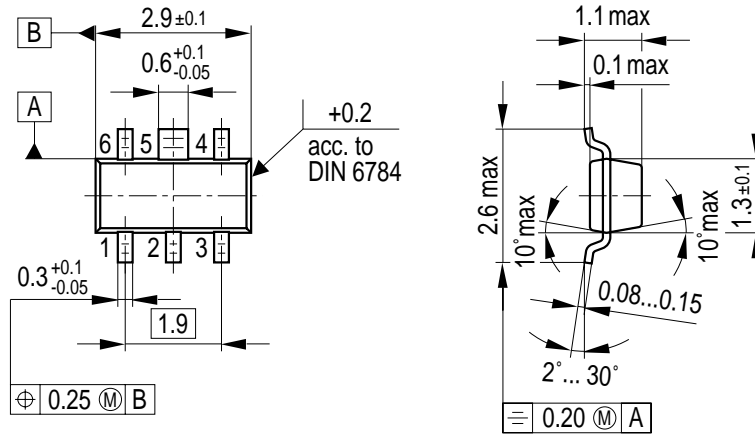


Total Power Dissipation
 $P_{\text{tot}} = f(T_{\text{s}})$



Package Outlines

MW-6
(Special Package)



GPW05794

Sorts of Packing

Package outlines for tubes, trays etc. are contained in our Data Book "Package Information".

SMD = Surface Mounted Device

Dimensions in mm